

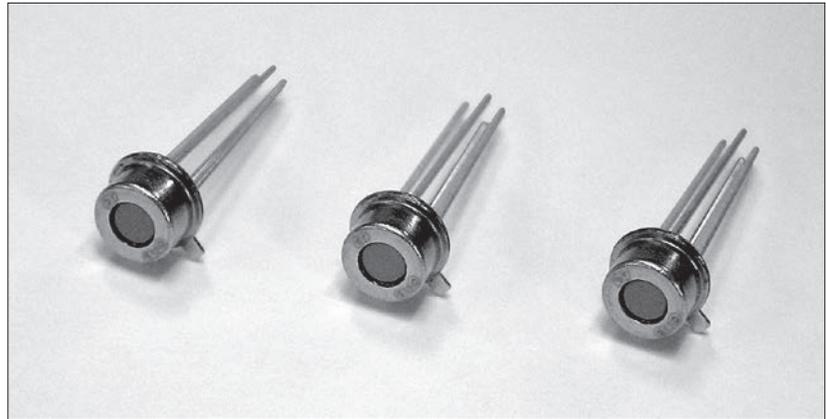
# Non-Contact (IR) Temperature Sensors

## THERMOPILE

Thermopiles use the same principle as thermocouples for IR temperature sensing. By using a SEMITEC original silicon-micromachining semiconductor process we have achieved higher output, faster response speed and a lower price.

### Applications

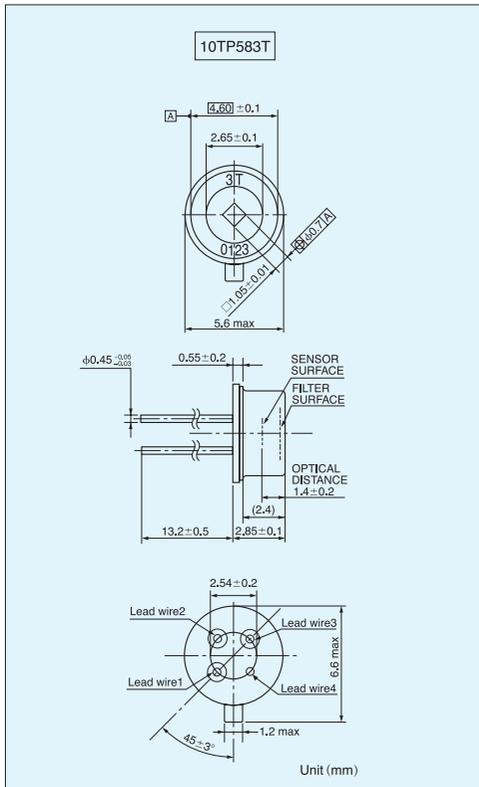
Ear thermometers, IR thermometers, microwave ovens and others



### Part number

Part No.	Type	Thermistor
10TP583T	TO18	Built-in

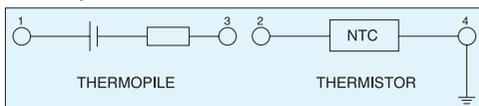
### Dimensions



### Ratings

Parameters	Value	Unit	Conditions
	10TP583T		
Sensitive area	1.05×1.05	mm <sup>2</sup>	Size of Absorbing Film
*1 Responsivity	15±30%	V/W	
*1 Output Voltage	200±30%	μV	
*2 Output Voltage	1.00±30%	mV	
*1 Temperature Coefficient of Responsivity	0.02±0.02	% / °C	Reference
Thermopile Resistance	65±30%	kΩ	
Temperature Coefficient of Thermopile Resistance	±0.1	% / °C	
Johnson Noise Voltage	33	nV / √Hz	Johnson Noise r.m.s., 298K 1Hz Typical
*1 S/N Ratio	75.7	dB	Output Voltage/Johnson Noise, Typical
*1 Noise Equivalent Power	2.2	nW/Hz <sup>1/2</sup>	Typical
*1 Specific Detectivity	4.7×10 <sup>7</sup>	cm·Hz <sup>1/2</sup> /w	Typical
Time Constant	15	ms	Typical
Operating Temperature range	-20~+100	°C	
Storage Temperature range	-40~+100	°C	
Filter Range	Cut on 5	μm	Standard
Field of View	±50	deg.	Incident Angle to Achieve 50% Responsivity
Insulation Resistance	≥500	MΩ	Application of DC25V
Sealing	≤1×10 <sup>-9</sup>	Pa·m <sup>3</sup> /s	
*3 Thermistor Resistance Value	100±3%	kΩ	Rated Zero-power Resistance Value at 25°C
*3 Thermistor B-Value	3435±0.7%	K	
*3 Thermistor Rated Power	0.5	mW	at 25°C

### Circuit layout



\*1 Test Conditions  
 Black Body Furnace : 500K  
 Sensor - Blackbody Distance : 100mm  
 Sensor Temperature : 298K  
 Aperture Size : φ12.7mm

\*2 Test Conditions  
 Black Body Furnace : 310K  
 Sensor Temperature : 298K